

YJ Planar Schottky Barrier Diode Die Specification

150V 2A, 45mil, Schottky barrier diode die based on silicon planar process
Part No.: PSB045H150SS-280A

Main Products Characterstics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 2\text{ A}$

2%

Device Schematics and Outline Drawing

Die Thickness *

Die Size **

Top Metal Pad

Active Area

Top Metal

Bac20.2 530.811.16 rev 3.0 (Bac)D [Bac20.2 530.81sng (x-none)BD